Onsemi

Complementary Silicon Power Transistors

D44VH10 (NPN), **D45VH10 (PNP)**

These complementary silicon power transistors are designed for high-speed switching applications, such as switching regulators and high frequency inverters. The devices are also well-suited for drivers for high power switching circuits.

Features

- Fast Switching
- Key Parameters Specified @ 100 °C
- Low Collector-Emitter Saturation Voltage
- Complementary Pairs Simplify Circuit Designs
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	80	Vdc
Collector-Emitter Voltage	V _{CEV}	100	Vdc
Emitter Base Voltage	V_{EB}	7.0	Vdc
Collector Current – Continuous	Ι _C	15	Adc
Collector Current – Peak (Note 1)	I _{CM}	20	Adc
Total Power Dissipation @ T _C = 25 °C Derate above 25 °C	P _D	83 0.67	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to 150	°C

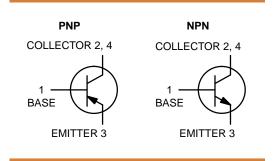
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Pulse Width \leq 6.0 ms, Duty Cycle \leq 50%.

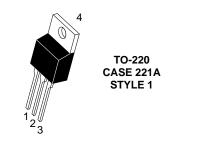
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R_{\thetaJC}	1.5	°C/W
Thermal Resistance, Junction to Ambient	R_{\thetaJA}	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	ΤL	275	°C

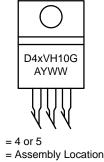
*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

15 A **COMPLEMENTARY SILICON** POWER TRANSISTORS 80 V, 83 W





MARKING DIAGRAM



А

Υ = Year

х

WW = Work Week

= Pb-Free Package G

ORDERING INFORMATION

Device	Package	Shipping
D44VH10G	TO-220 (Pb-Free)	50 Units/Rail
D45VH10G	TO-220 (Pb-Free)	50 Units/Rail

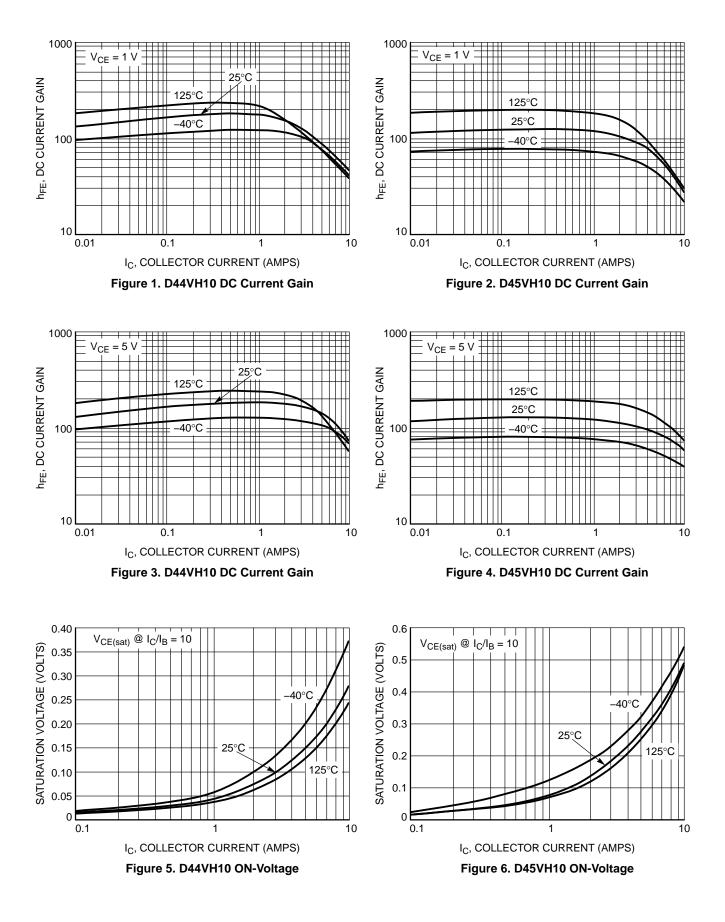
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ELECTRICAL CHARACTERISTICS (T_C = 25 °C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage (Note 2) $(I_C = 25 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	80	-	-	Vdc
$ Collector-Emitter Cutoff Current \\ (V_{CE} = Rated V_{CEV}, V_{BE(off)} = 4.0 \text{ Vdc}) \\ (V_{CE} = Rated V_{CEV}, V_{BE(off)} = 4.0 \text{ Vdc}, T_C = 100 \text{ °C}) $	I _{CEV}			10 100	μAdc
Emitter Base Cutoff Current ($V_{EB} = 7.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	_	10	μAdc
ON CHARACTERISTICS (Note 2)					
DC Current Gain ($I_C = 2.0 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 4.0 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc}$)	h _{FE}	35 20			-
Collector-Emitter Saturation Voltage	V _{CE(sat)}				Vdc
(I _C = 8.0 Adc, I _B = 0.4 Adc) D44VH10		-	-	0.4	
(I _C = 8.0 Adc, I _B = 0.8 Adc) D45VH10 (I _C = 15 Adc, I _B = 3.0 Adc, T _C = 100 °C)		-	-	1.0	
D44VH10 D45VH10		-	-	0.8 1.5	
Base-Emitter Saturation Voltage	V _{BE(sat)}				Vdc
(I _C = 8.0 Adc, I _B = 0.4 Adc) D44VH10 (I _C = 8.0 Adc, I _B = 0.8 Adc)		-	-	1.2	
D45VH10 (I _C = 8.0 Adc, I _B = 0.4 Adc, T _C = 100 °C)		-	-	1.0	
D44VH10 (I _C = 8.0 Adc, I _B = 0.8 Adc, T _C = 100 °C) D45VH10		-	-	1.1 1.5	
DYNAMIC CHARACTERISTICS	1	l	1	1	
Current Gain Bandwidth Product ($I_C = 0.1 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 20 \text{ MHz}$)	f _T	_	50	_	MHz
Output Capacitance	C _{ob}				pF
(V _{CB} = 10 Vdc, I _C = 0, f _{test} = 1.0 MHz) D44VH10 D45VH10		- -	120 275	- -	
SWITCHING CHARACTERISTICS		-			
Delay Time	t _d	_	_	50	ns
Rise Time $(V_{CC} = 20 \text{ Vdc}, I_C = 8.0 \text{ Adc}, I_{B1} = I_{B2} = 0.8 \text{ Adc})$	t _r	-	_	250]
Storage Time $(V_{CC} = 20$ Vac, $I_C = 8.0$ Adc, $I_{B1} = I_{B2} = 0.6$ Adc)	ts	-	_	700]
Fall Time	t _f	-	-	90	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

D44VH10 (NPN), D45VH10 (PNP)



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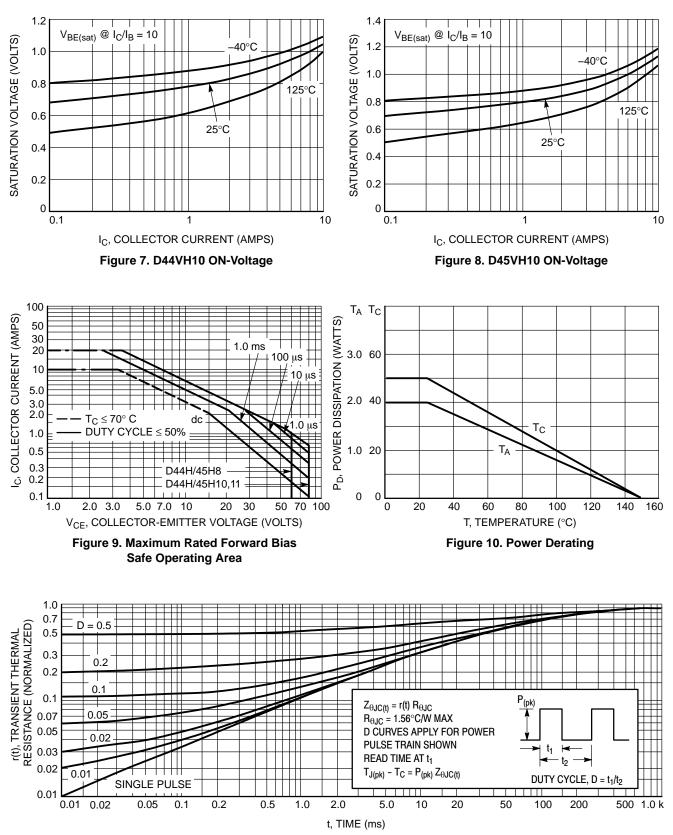
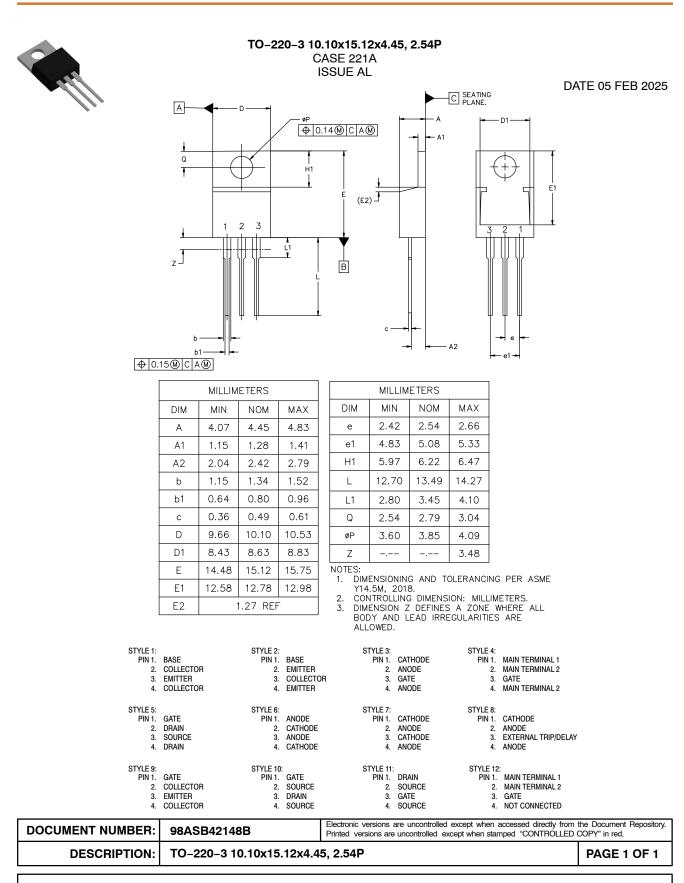


Figure 11. Thermal Response





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